

NTE3100 Photon Coupled Interrupter Module

Description:

The NTE3100 Interrupter Module is a gallium arsenide infrared emitting diode and a NPN silicon photo transistor mounted is a polycarbonate housing. The package is designed to optimize the mechanical resolution, coupling efficiency, ambient light rejection, cost and reliability. Operating on the principle that opaque to infrared will interrupt the transmission of light between an infrared emitting diode and a photo sensor switching the output from an "ON" state to an "OFF" state.

Features:

- High Gain
- 3mm Gap Between LED and Detector
- Polycarbonate Case Protected Against Ambient Light

Applications:

Copiers, Printers, FAX Machines, Record Players, Cassette Decks, Optoelectronic Switches

Absolute Maximum Ratings: $(T_A = +25^{\circ}C \text{ unless otherwise specified})$

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<u>Electrical Characteristics:</u> $(T_A = +25^{\circ}C \text{ unless otherwise specified})$

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Input							
Forward Voltage	V _F	I _F = 50mA	_	1.2	1.7	V	
Reverse Voltage	V_{R}	I _R = 100μA	5	_	_	V	
Reverse Current	I _R	V _R = 5V	_	_	100	μΑ	
Output							
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	I _C = 1mA	30	_	_	V	
Emitter-Collector Breakdown Voltage	V _{(BR)ECO}	$I_E = 100\mu A$	6	_	_	V	
Collector-Emitter Dark Current	I _{CEO}	V _{CE} = 10V	_	_	100	nA	
Coupled							
Collector "ON" Current	I _{CE(on)}	$I_F = 5mA$, $V_{CE} = 5V$	0.15	_	_	mA	
		I _F = 20mA, V _{CE} = 5V	1.0	_	_	mA	
		$I_F = 30 \text{mA}, V_{CE} = 5 \text{V}$	1.9	_	_	mA	
Collector-Emitter Saturation Voltage	V _{CE(sat)}	$I_F = 30 \text{mA}, I_C = 1.8 \text{mA}$	_	_	0.4	V	
Turn-On Time	t _{on}	V_{CC} = 5V, I_F = 30mA, R_L = 2.5k Ω	_	8	_	μs	
Turn-Off Time	t _{off}		_	50	_	μs	

